

MJD112 (NPN) MJD117 (PNP)

Preferred Device

Complementary Darlington Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("–1" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V_{CEO}	100	Vdc
Collector–Base Voltage	V_{CB}	100	Vdc
Emitter–Base Voltage	V_{EB}	5	Vdc
Collector Current – Continuous – Peak	I_C	2 4	Adc
Base Current	I_B	50	mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	20 0.16	W W/ $^\circ\text{C}$
Total Power Dissipation (Note1) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.75 0.014	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	71.4	$^\circ\text{C/W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

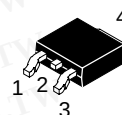


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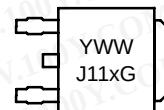
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**SILICON
POWER TRANSISTORS
2 AMPERES
100 VOLTS, 20 WATTS**

MARKING DIAGRAMS



**DPAK
CASE 369C**



**DPAK-3
CASE 369D**

Y = Year
WW = Work Week
x = 2 or 7
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 2) ($I_C = 30\text{ mAdc}$, $I_B = 0$)	$V_{CE(sus)}$	100	—	Vdc
Collector Cutoff Current ($V_{CE} = 50\text{ Vdc}$, $I_B = 0$)	I_{CEO}	—	20	μAdc
Collector Cutoff Current ($V_{CB} = 100\text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	20	μAdc
Emitter Cutoff Current ($V_{BE} = 5\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	2	mAdc
Collector-Cutoff Current ($V_{CB} = 80\text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	10	μAdc
Emitter-Cutoff Current ($V_{BE} = 5\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	2	mAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = 0.5\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$) ($I_C = 2\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$) ($I_C = 4\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$)	h_{FE}	500 1000 200	— 12,000 —	—
Collector-Emitter Saturation Voltage ($I_C = 2\text{ Adc}$, $I_B = 8\text{ mAdc}$) ($I_C = 4\text{ Adc}$, $I_B = 40\text{ mAdc}$)	$V_{CE(sat)}$	— —	2 3	Vdc
Base-Emitter Saturation Voltage ($I_C = 4\text{ Adc}$, $I_B = 40\text{ mAdc}$)	$V_{BE(sat)}$	—	4	Vdc
Base-Emitter On Voltage ($I_C = 2\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$)	$V_{BE(on)}$	—	2.8	Vdc

DYNAMIC CHARACTERISTICS

Current-Gain - Bandwidth Product ($I_C = 0.75\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f = 1\text{ MHz}$)	f_T	25	—	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 0.1\text{ MHz}$)	C_{ob}	— —	200 100	pF
	MJD117 MJD112			

2. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$.

*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

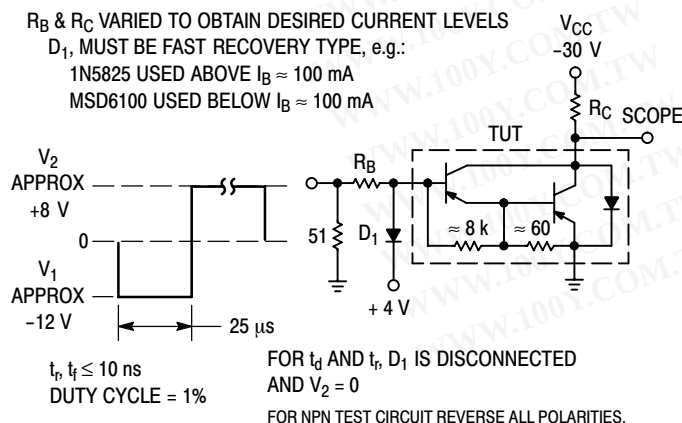


Figure 1. Switching Times Test Circuit

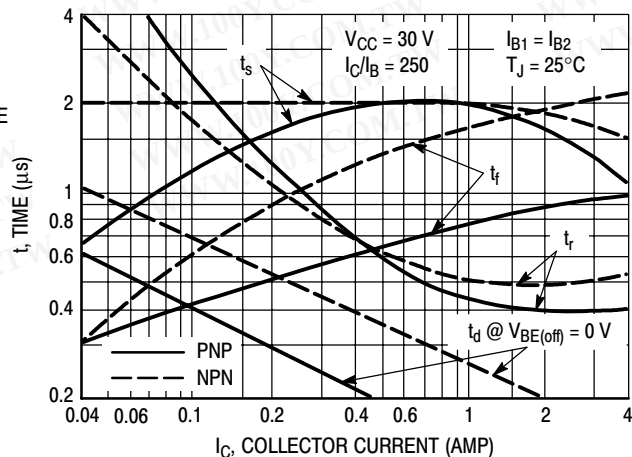


Figure 2. Switching Times

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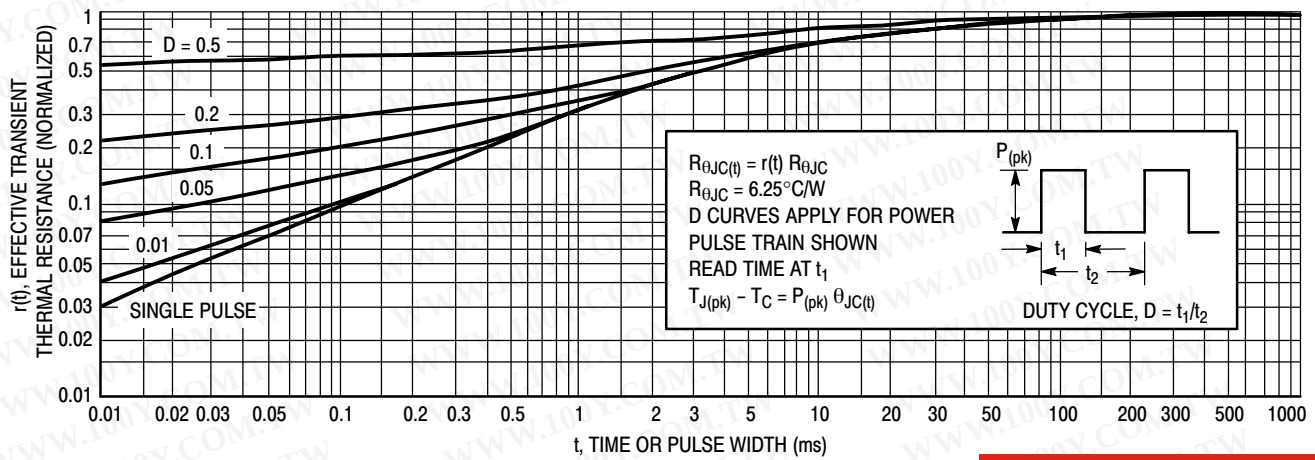


Figure 3. Thermal Response

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ACTIVE-REGION SAFE-OPERATING AREA

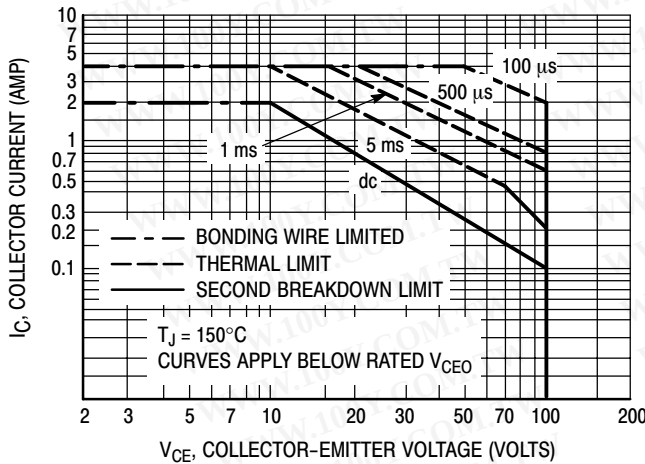


Figure 4. Maximum Rated Forward Biased Safe Operating Area

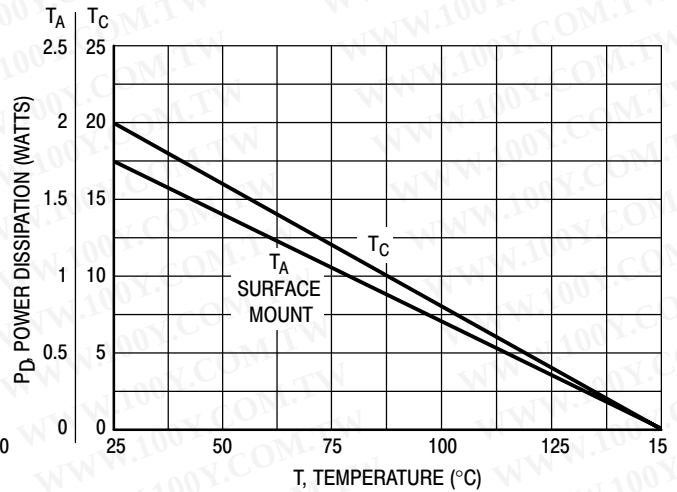


Figure 5. Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 5 and 6 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

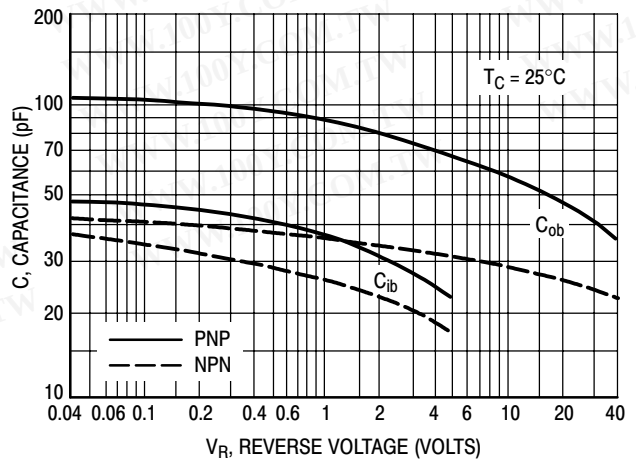


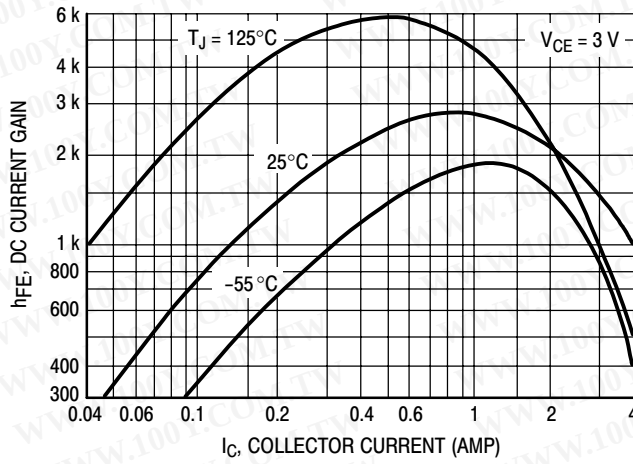
Figure 6. Capacitance

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TYPICAL ELECTRICAL CHARACTERISTICS

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NPN MJD112



PNP MJD117

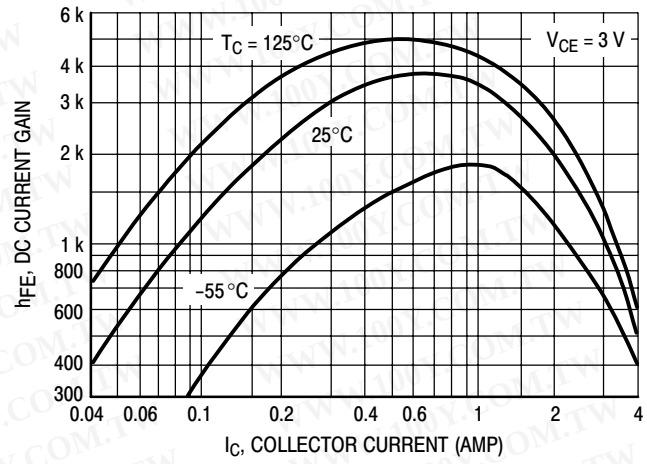


Figure 7. DC Current Gain

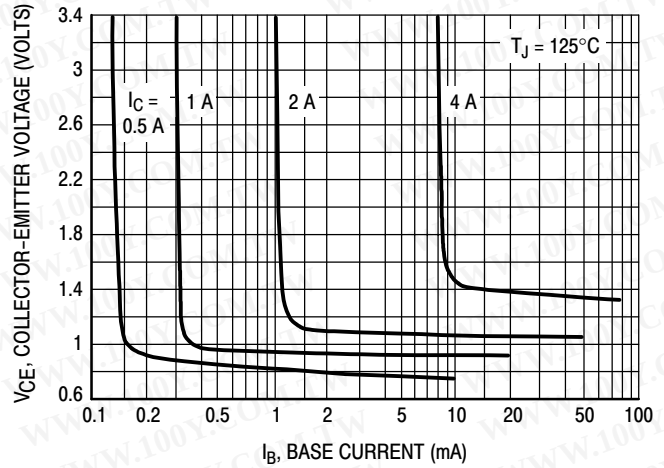
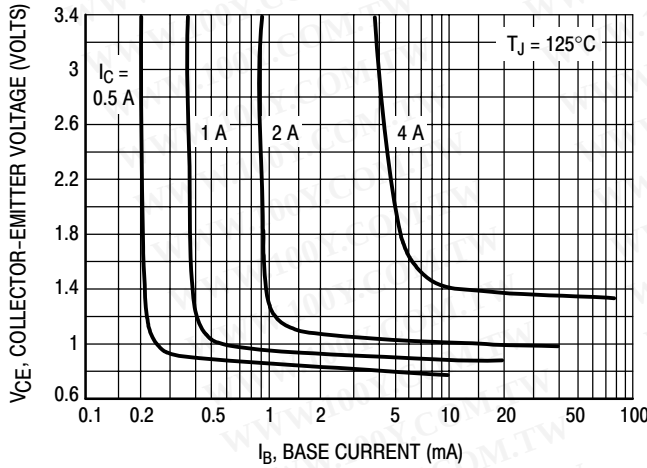


Figure 8. Collector Saturation Region

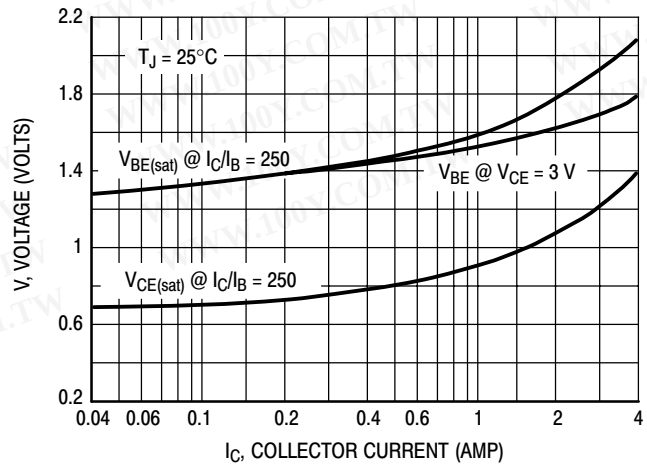
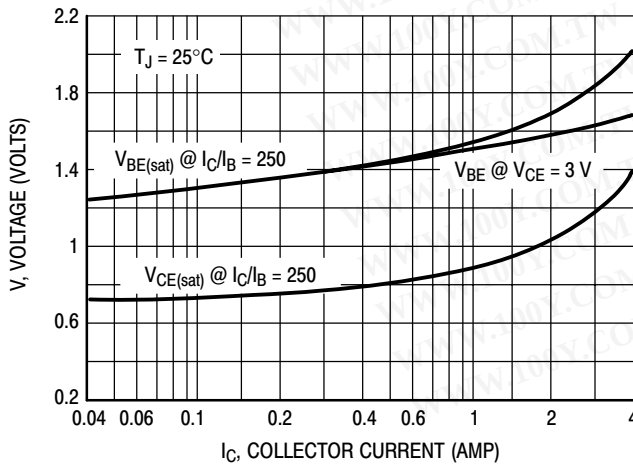
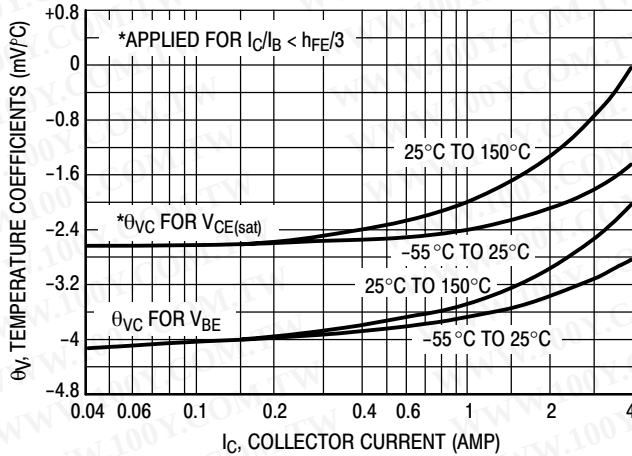


Figure 9. "On Voltages"

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NPN MJD112



PNP MJD117

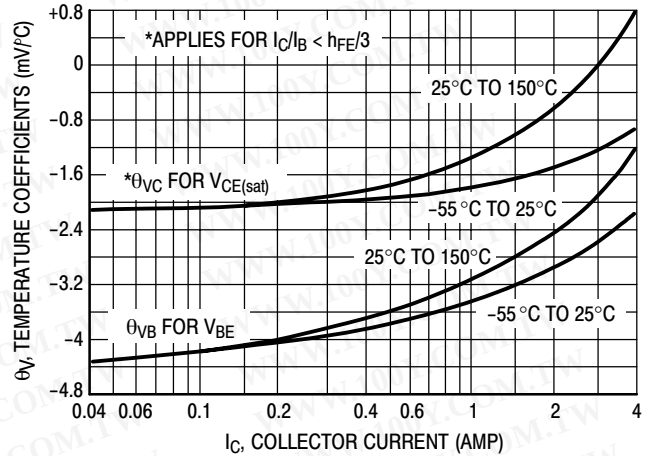


Figure 10. Temperature Coefficients

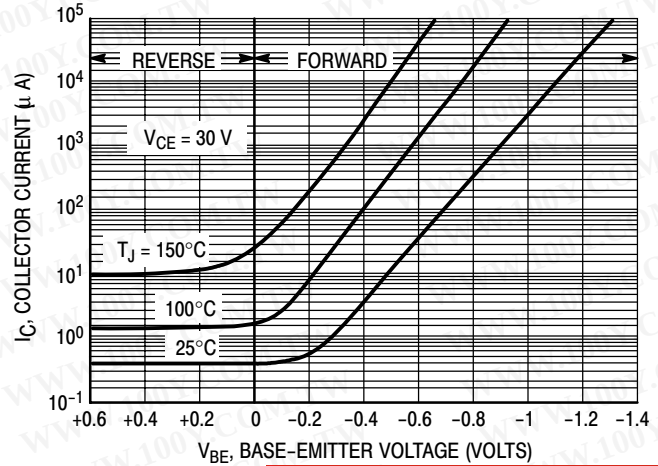
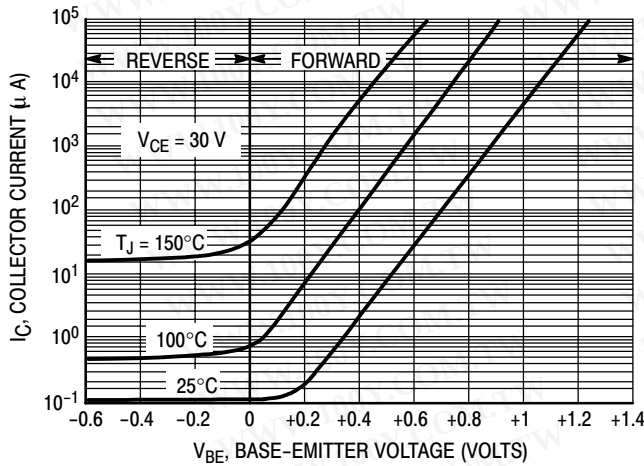


Figure 11. Collector Cut-Off Region

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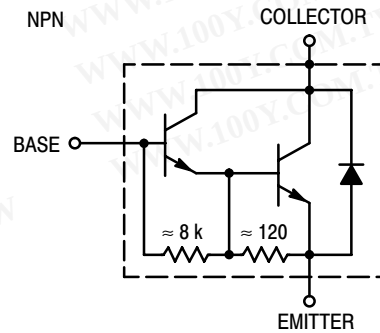
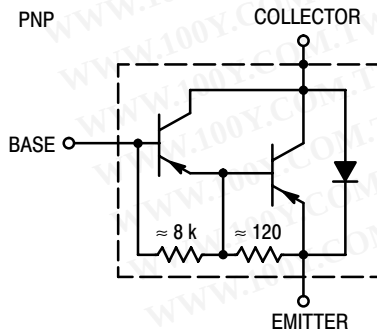


Figure 12. Darlington Schematic

MJD112 (NPN) MJD117 (PNP)

ORDERING INFORMATION

Device	Package Type	Package	Shipping†
MJD112	DPAK	369C	75 Units / Rail
MJD112G	DPAK (Pb-Free)		
MJD112-001	DPAK-3	369D	
MJD112-1G	DPAK-3 (Pb-Free)		
MJD112RL	DPAK	369C	1800 Tape & Reel
MJD112RLG	DPAK (Pb-Free)		
MJD112T4	DPAK		2500 Tape & Reel
MJD112T4G	DPAK (Pb-Free)		
MJD117	DPAK		75 Units / Rail
MJD117G	DPAK (Pb-Free)		
MJD117-001	DPAK-3	369D	
MJD117-1G	DPAK-3 (Pb-Free)		
MJD117T4	DPAK	369C	2500 Tape & Reel
MJD117T4G	DPAK (Pb-Free)		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

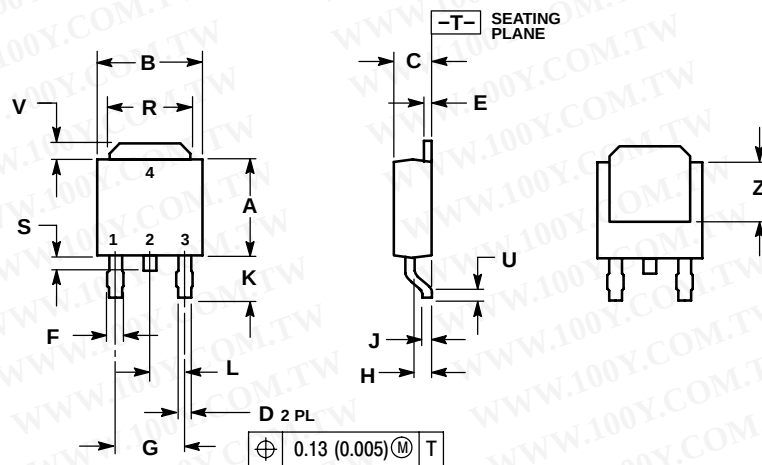
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PACKAGE DIMENSIONS

DPAK
CASE 369C
ISSUE O

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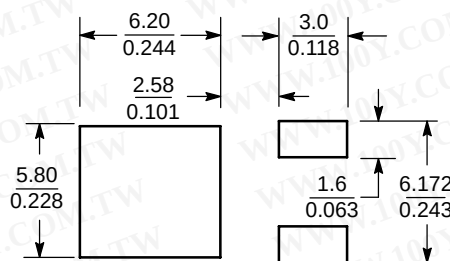


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

SOLDERING FOOTPRINT*



SCALE 3:1 (mm/inches)

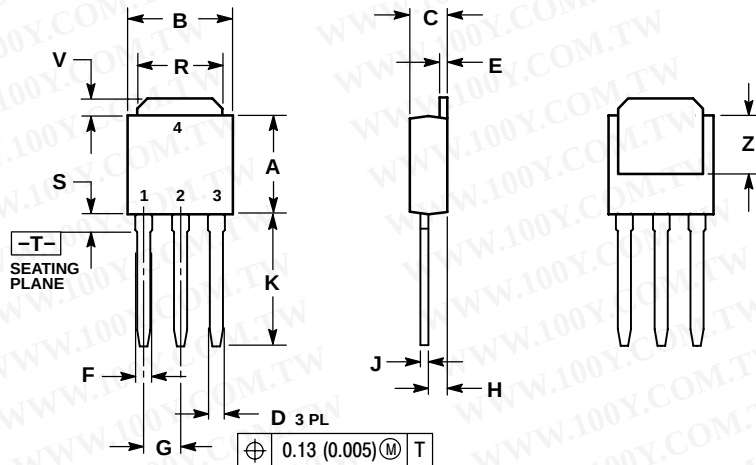
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MJD112 (NPN) MJD117 (PNP)

PACKAGE DIMENSIONS

DPAK-3
CASE 369D-01
ISSUE B

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B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29	BSC
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

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